

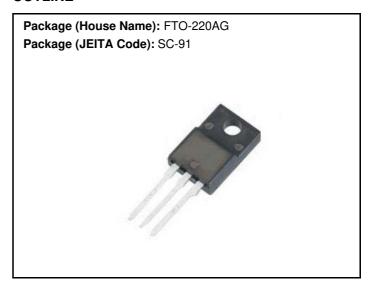
P5F50HP2F

Power MOSFETs 500V, 5A, N-channel

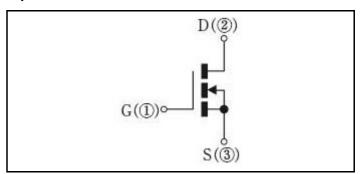
Feature

- N-channel
- High Speed Source-Drain Diode
- · High Speed Switching
- · Low Capacitance
- High Avalanche Durability, High di/dt Durability
- Pb free terminal
- RoHS:Yes

OUTLINE



Equivalent circuit



$\textbf{Absolute Maximum Ratings} \quad \text{(unless otherwise specified : } Tc=25\,^{\circ}C)$

Item	Symbol	Conditions	Ratings	Unit
Storage temperature	Tstg		-55 to 150	°C
Channel tempertature	Tch		150 °C	
Drain-source voltage	V_{DSS}		500 V	
Gate-source voltage	V _{GSS}		±30 V	
Continuous drain current(DC)	I _D		5 A	
Continuous drain current(Peak)	I _{DP}	Pulse width 10µs, duty=1/100	20	Α
Continuous source current(DC)	ls		5 A	
Total power dissipation	P _T		52.5 W	
Repetitive avalanche current	I _{AR}	Starting Tch=25°C Tch≦150°C	5 A	
Single avalanche energy	E _{AS}	Starting Tch=25°C Tch≦150°C	45 m.	
Repetitive avalanche energy	E _{AR}	Starting Tch=25°C Tch≦150°C	4.5	mJ
Drain-source diode di/dt strength	di/dt	Is=5A, Tc=25°C	350 A/	
Dielectric strenght	Vdis	Terminals to case, AC1min	2 kV	
Mounting torque	TOR	(Recommended torque : 0.3N⋅m)	0.5 N·m	

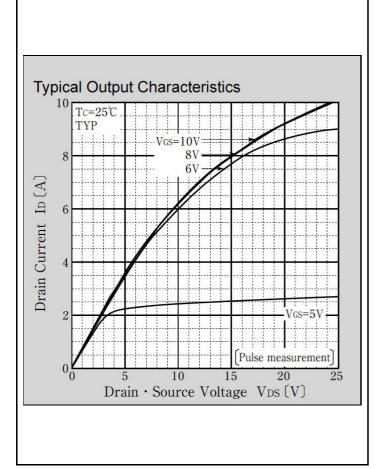
^{* :}See the original Specifications

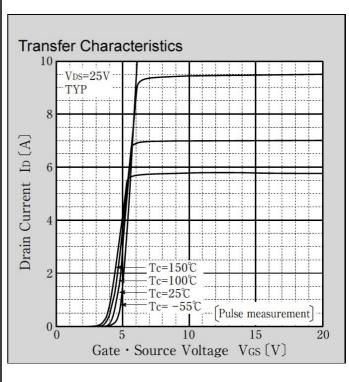
Electrical Characteristics (unless otherwise specified : Tc=25°C)

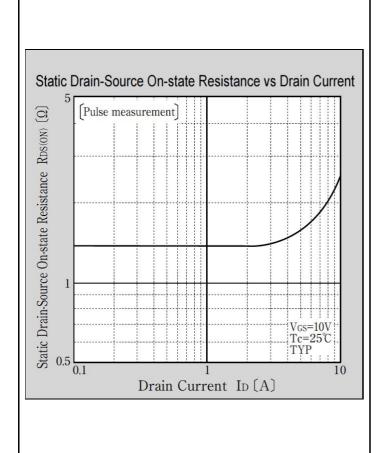
Item	Symbol	Conditions	Ratings			Unit
			MIN	TYP	MAX	Oilit
Drain-Source breakdown voltage	V _{(BR)DSS}	ID=1mA, VGS=0V	500			V
Zero gate voltage drain current	I _{DSS}	VDS=500V, VGS=0V			100	μΑ
Gate-source leakage current	I _{GSS}	VGS=±25V, VDS=0V			±10	μΑ
Forward transconductance	9 _{fs}	ID=2.5A, VDS=10V	2.5	5		S
Static drain-source on-state resistance	R _{DS(ON)}	ID=2.5A, VGS=10V		1.38	1.65	Ω
Gate threshold voltage	Vth	ID=1mA, VDS=10V	2	3.25	4.5	٧
Source-drain diode forward voltage	V _{SD}	IS=2.5A, VGS=0V			1.5	V
Thermal resistance	Rth(j-c)	Junction to case			2.38	°C/W
Total gate charge	Qg	VDD=400V, VGS=10V, ID=5A		10.5		nC
Input capacitance	Ciss	VDS=50V, VGS=0V, f=1MHz		405		pF
Reverce transfer capacitnce	Crss	VDS=50V, VGS=0V, f=1MHz		4		pF
Output capacitance	Coss	VDS=50V, VGS=0V, f=1MHz		45		pF
Turn-on delay time	td(on)	ID=2.5A, RL=60Ω, VDD=150V, Rg=50Ω, VGS(+)=10V, VGS(-)=0V		9		ns
Rise time	tr	ID=2.5A, RL=60Ω, VDD=150V, Rg=50Ω, VGS(+)=10V, VGS(-)=0V		11		ns
Turn-off delay time	td(off)	ID=2.5A, RL=60Ω, VDD=150V, Rg=50Ω, VGS(+)=10V, VGS(-)=0V		35		ns
Fall time	tf	ID=2.5A, RL=60Ω, VDD=150V, Rg=50Ω, VGS(+)=10V, VGS(-)=0V		22		ns
Diode reverse recovery time	trr	IF=5A, VGS=0V, di/dt=100A/μs		70		ns

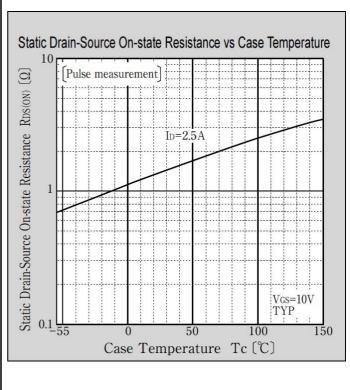
st :See the original Specifications

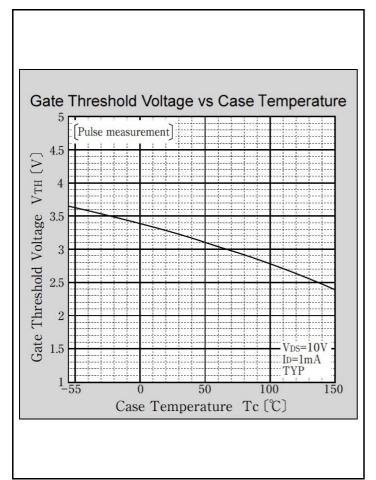
CHARACTERISTIC DIAGRAMS

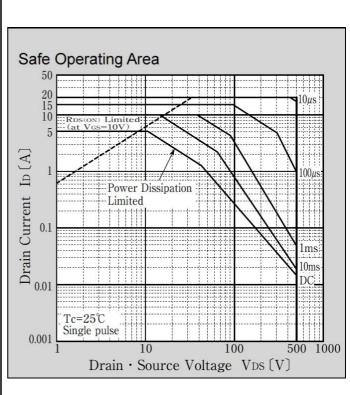


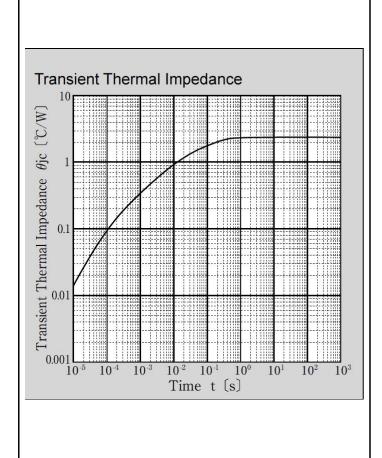


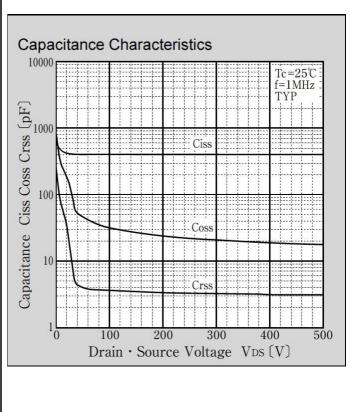


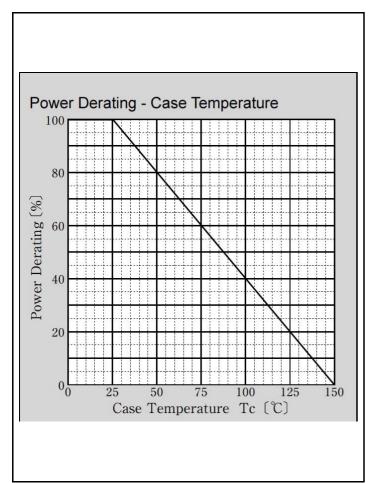


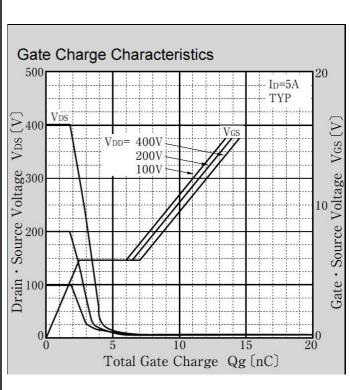


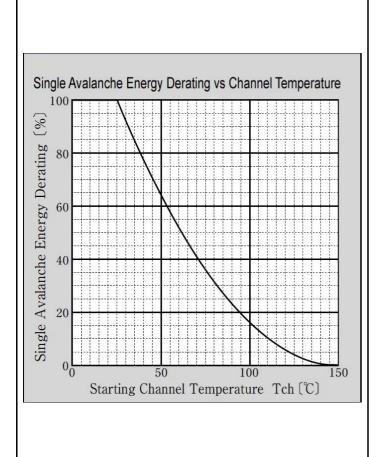


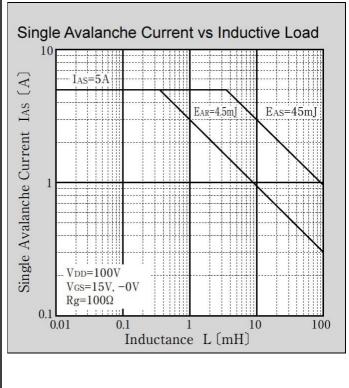










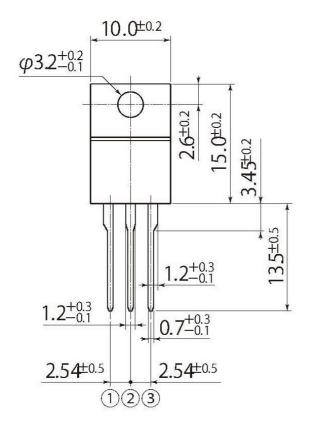


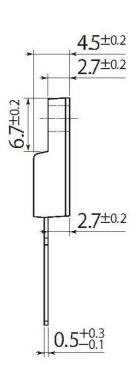
unit:mm

scale: 2/1

J8

JEDEC Code	-		
JEITA Code	SC-91		
House Name	FTO-220AG(3pin)		





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